

Dual 4-Channel Data Selector/Multiplexer

The MC14539B data selector/multiplexer is constructed with MOS P-channel and N-channel enhancement mode devices in a single monolithic structure. The circuit consists of two sections of four inputs each. One input from each section is selected by the address inputs A and B. A "high" on the Strobe input will cause the output to remain "low".

This device finds primary application in signal multiplexing functions. It permits multiplexing from N-lines to I-line, and can also perform parallel-to-serial conversion. The Strobe input allows cascading of n-lines to n-lines.

- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low-Power TTL Loads or One Low-Power Schottky TTL Load Over the Rated Temperature Range

MAXIMUM RATINGS* (Voltages Referenced to V_{SS})

Symbol	Parameter	Value	Unit
V _{DD}	DC Supply Voltage	− 0.5 to + 18.0	V
V _{in} , V _{out}	Input or Output Voltage (DC or Transient)	− 0.5 to V _{DD} + 0.5	V
I _{in} , I _{out}	Input or Output Current (DC or Transient), per Pin	± 10	mA
P _D	Power Dissipation, per Package†	500	mW
T _{stg}	Storage Temperature	− 65 to + 150	°C
T _L	Lead Temperature (8-Second Soldering)	260	°C

* Maximum Ratings are those values beyond which damage to the device may occur.

† Temperature Derating:

Plastic "P and D/DW" Packages: − 7.0 mW/°C From 65°C To 125°C

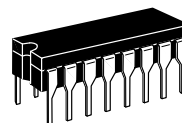
Ceramic "L" Packages: − 12 mW/°C From 100°C To 125°C

TRUTH TABLE

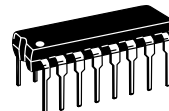
Address Inputs		Data Inputs				ST, ST'	Outputs Z, W
B	A	X3 Y3	X2 Y2	X1 Y1	X0 Y0		
X	X	X	X	X	X	1	0
0	0	X	X	X	0	0	0
0	0	X	X	X	1	0	1
0	1	X	X	0	X	0	0
0	1	X	X	1	X	0	1
1	0	X	0	X	X	0	0
1	0	X	1	X	X	0	1
1	1	0	X	X	X	0	0
1	1	1	X	X	X	0	1

X = Don't Care

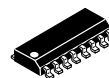
MC14539B



L SUFFIX
CERAMIC
CASE 620



P SUFFIX
PLASTIC
CASE 648



D SUFFIX
SOIC
CASE 751B

ORDERING INFORMATION

MC14XXXBCP

Plastic

MC14XXXBCL

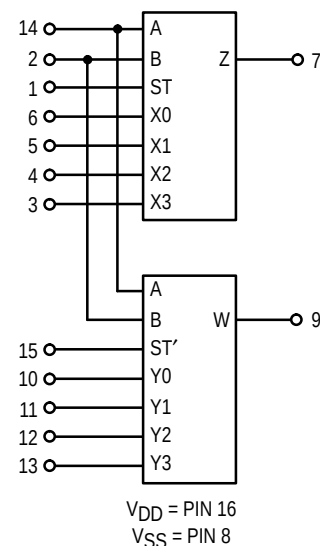
Ceramic

MC14XXXBD

SOIC

T_A = − 55° to 125°C for all packages.

BLOCK DIAGRAM



ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

Characteristic	Symbol	V_{DD} Vdc	– 55°C		25°C			125°C		Unit
			Min	Max	Min	Typ #	Max	Min	Max	
Output Voltage $V_{in} = V_{DD}$ or 0	VOL	5.0	—	0.05	—	0	0.05	—	0.05	Vdc
		10	—	0.05	—	0	0.05	—	0.05	
		15	—	0.05	—	0	0.05	—	0.05	
	VOH	5.0	4.95	—	4.95	5.0	—	4.95	—	Vdc
		10	9.95	—	9.95	10	—	9.95	—	
		15	14.95	—	14.95	15	—	14.95	—	
Input Voltage ($V_O = 4.5$ or 0.5 Vdc) ($V_O = 9.0$ or 1.0 Vdc) ($V_O = 13.5$ or 1.5 Vdc)	VIL	5.0	—	1.5	—	2.25	1.5	—	1.5	Vdc
		10	—	3.0	—	4.50	3.0	—	3.0	
		15	—	4.0	—	6.75	4.0	—	4.0	
	VIH	5.0	3.5	—	3.5	2.75	—	3.5	—	Vdc
		10	7.0	—	7.0	5.50	—	7.0	—	
		15	11	—	11	8.25	—	11	—	
Output Drive Current ($V_{OH} = 2.5$ Vdc) ($V_{OH} = 4.6$ Vdc) ($V_{OH} = 9.5$ Vdc) ($V_{OH} = 13.5$ Vdc)	Source IOH	5.0	– 3.0	—	– 2.4	– 4.2	—	– 1.7	—	mAdc
		5.0	– 0.64	—	– 0.51	– 0.88	—	– 0.36	—	
		10	– 1.6	—	– 1.3	– 2.25	—	– 0.9	—	
		15	– 4.2	—	– 3.4	– 8.8	—	– 2.4	—	
	Sink IOL	5.0	0.64	—	0.51	0.88	—	0.36	—	mAdc
		10	1.6	—	1.3	2.25	—	0.9	—	
		15	4.2	—	3.4	8.8	—	2.4	—	
Input Current	Iin	15	—	±0.1	—	±0.00001	±0.1	—	±1.0	μAdc
Input Capacitance ($V_{in} = 0$)	Cin	—	—	—	—	5.0	7.5	—	—	pF
Quiescent Current (Per Package)	IDD	5.0	—	5.0	—	0.005	5.0	—	150	μAdc
		10	—	10	—	0.010	10	—	300	
		15	—	20	—	0.015	20	—	600	
Total Supply Current**† (Dynamic plus Quiescent, Per Package) ($C_L = 50$ pF on all outputs, all buffers switching)	IT	5.0 10 15	$I_T = (0.85 \mu A/kHz) f + I_{DD}$ $I_T = (1.70 \mu A/kHz) f + I_{DD}$ $I_T = (2.60 \mu A/kHz) f + I_{DD}$							μAdc

#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

**The formulas given are for the typical characteristics only at 25°C.

†To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) V_{fk}$$

where: I_T is in μA (per package), C_L in pF, $V = (V_{DD} - V_{SS})$ in volts, f in kHz is input frequency, and $k = 0.002$.

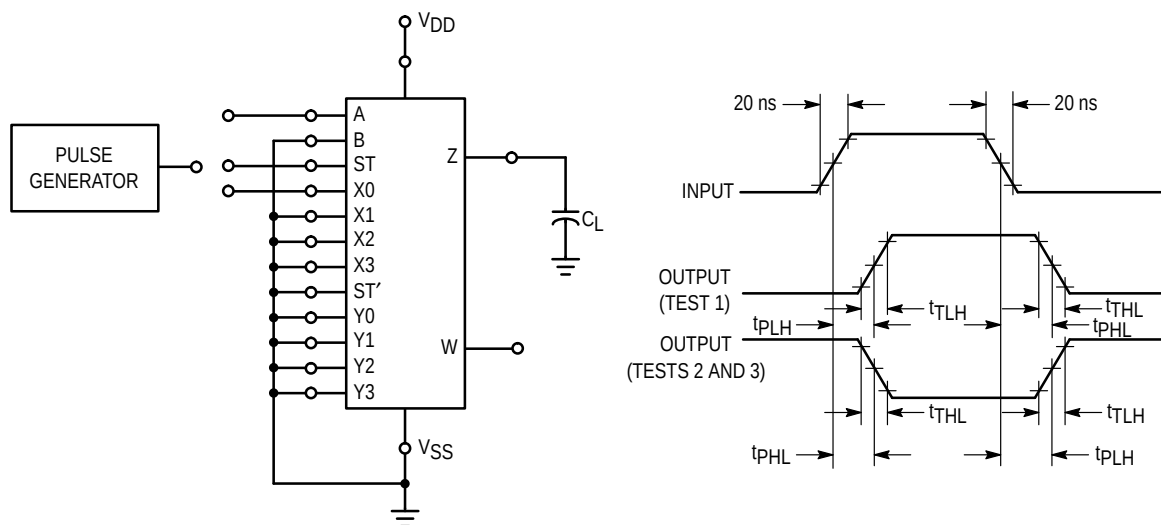
This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

SWITCHING CHARACTERISTICS* ($C_L = 50 \text{ pF}$, $T_A = 25^\circ\text{C}$)

Characteristic	Symbol	V_{DD}	Min	Typ #	Max	Unit
Output Rise and Fall Time t_{TLH} , $t_{THL} = (1.5 \text{ ns/pF}) C_L + 25 \text{ ns}$ t_{TLH} , $t_{THL} = (0.75 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ t_{TLH} , $t_{THL} = (0.55 \text{ ns/pF}) C_L + 9.5 \text{ ns}$	t_{TLH} , t_{THL}	5.0 10 15	— — —	100 50 40	200 100 80	ns
Propagation Delay Time X, Y Input to Output t_{PLH} , $t_{PHL} = (1.7 \text{ ns/pF}) C_L + 125 \text{ ns}$ t_{PLH} , $t_{PHL} = (0.66 \text{ ns/pF}) C_L + 57 \text{ ns}$ t_{PLH} , $t_{PHL} = (0.55 \text{ ns/pF}) C_L + 45 \text{ ns}$	t_{PLH} , t_{PHL}	5.0 10 15	— — —	210 90 70	420 180 140	ns
A Input to Output $t_{PLH} = (1.7 \text{ ns/pF}) C_L + 140 \text{ ns}$ $t_{PLH} = (0.66 \text{ ns/pF}) C_L + 77 \text{ ns}$ $t_{PLH} = (0.5 \text{ ns/pF}) C_L + 60 \text{ ns}$	t_{PLH}	5.0 10 15	— — —	225 110 85	450 220 170	ns
$t_{PHL} = (1.7 \text{ ns/pF}) C_L + 160 \text{ ns}$ $t_{PHL} = (0.66 \text{ ns/pF}) C_L + 82 \text{ ns}$ $t_{PHL} = (0.5 \text{ ns/pF}) C_L + 65 \text{ ns}$	t_{PHL}	5.0 10 15	— — —	245 115 90	490 230 180	ns
Strobe Input to Output t_{PLH} , $t_{PHL} = (1.7 \text{ ns/pF}) C_L + 60 \text{ ns}$ t_{PLH} , $t_{PHL} = (0.66 \text{ ns/pF}) C_L + 42 \text{ ns}$ t_{PLH} , $t_{PHL} = (0.5 \text{ ns/pF}) C_L + 35 \text{ ns}$	t_{PLH} , t_{PHL}	5.0 10 15	— — —	145 75 60	290 150 120	ns

* The formulas given are for the typical characteristics only at 25°C .

#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.



INPUT CONNECTIONS FOR t_{TLH} , t_{THL} , t_{PHL} , t_{PLH}

Test	Strobe	A	X0
1	Gnd	Gnd	P.G.
2	P.G.	Gnd	V_{DD}
3	Gnd	P.G.	V_{DD}

Figure 1. AC Test Circuit and Waveforms

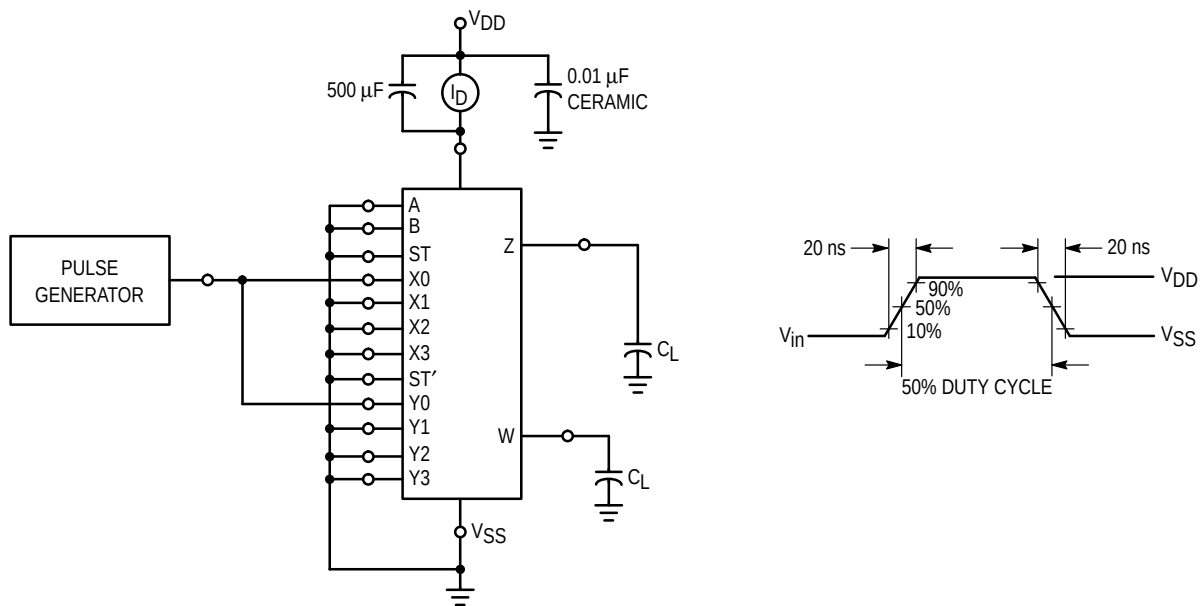
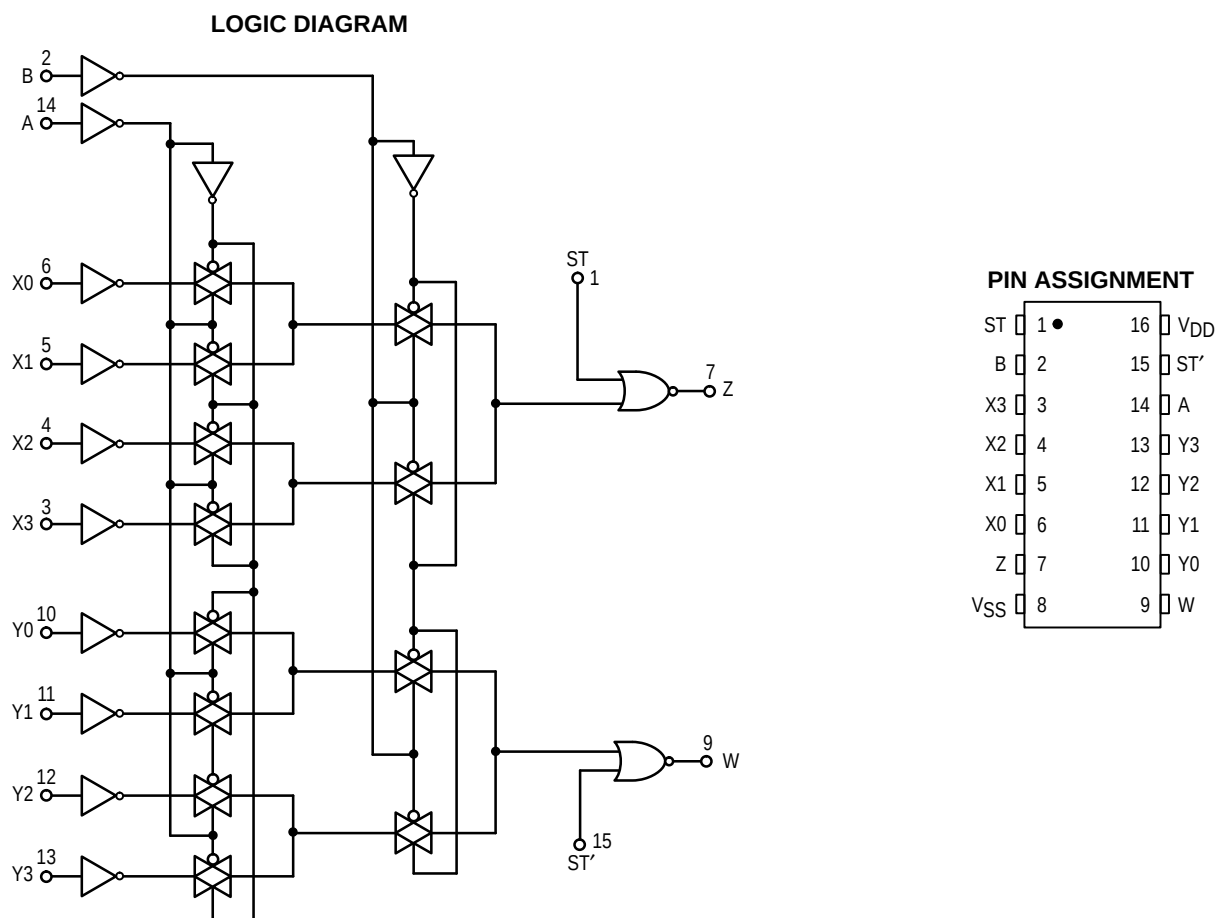
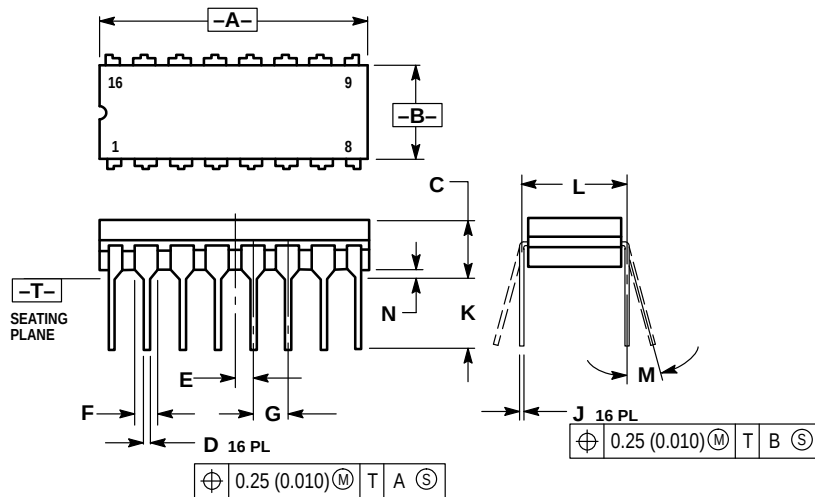


Figure 2. Power Dissipation Test Circuit and Waveform



OUTLINE DIMENSIONS

L SUFFIX CERAMIC DIP PACKAGE CASE 620-10 ISSUE V

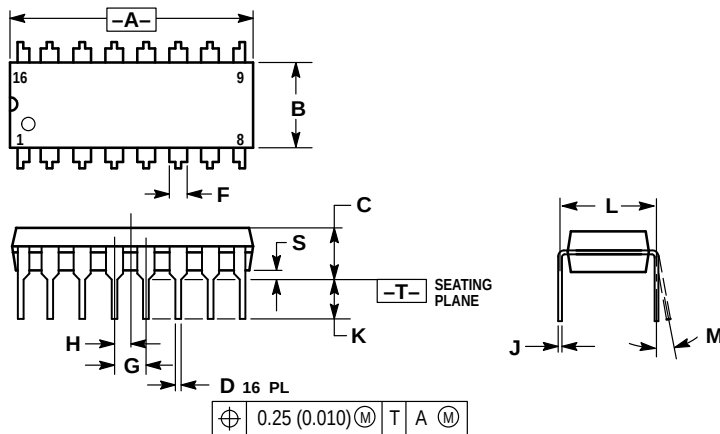


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
4. DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.750	0.785	19.05	19.93
B	0.240	0.295	6.10	7.49
C	—	0.200	—	5.08
D	0.015	0.020	0.39	0.50
E	0.050	BSC	1.27	BSC
F	0.055	0.065	1.40	1.65
G	0.100	BSC	2.54	BSC
H	0.008	0.015	0.21	0.38
K	0.125	0.170	3.18	4.31
L	0.300	BSC	7.62	BSC
M	0°	15°	0°	15°
N	0.020	0.040	0.51	1.01

P SUFFIX PLASTIC DIP PACKAGE CASE 648-08 ISSUE R



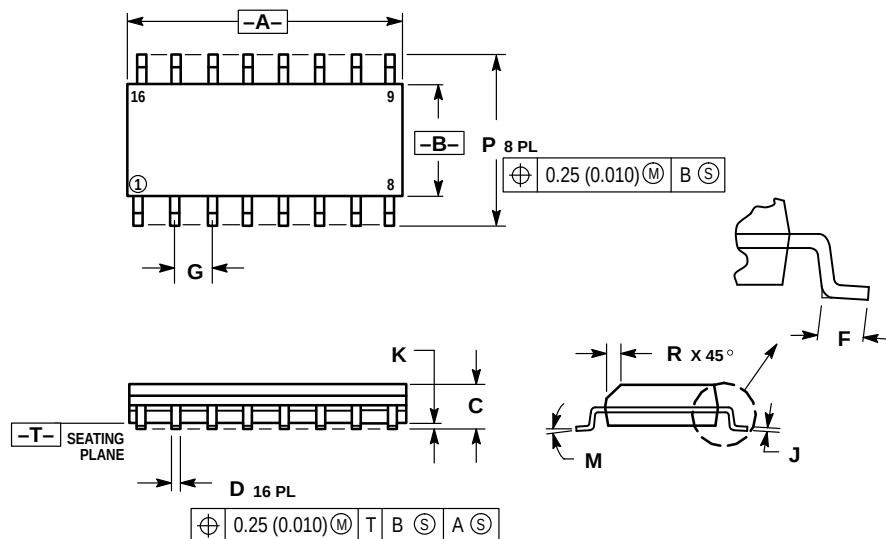
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.740	0.770	18.80	19.55
B	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100	BSC	2.54	BSC
H	0.050	BSC	1.27	BSC
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0°	10°	0°	10°
S	0.020	0.040	0.51	1.01

OUTLINE DIMENSIONS

D SUFFIX PLASTIC SOIC PACKAGE CASE 751B-05 ISSUE J



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MC14539B/D

